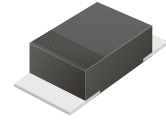


CDBMT120-HF Thru. CDBMT1150-HF

Reverse Voltage: 20 to 150 Volts

Forward Current: 1.0 Amp

RoHS Device

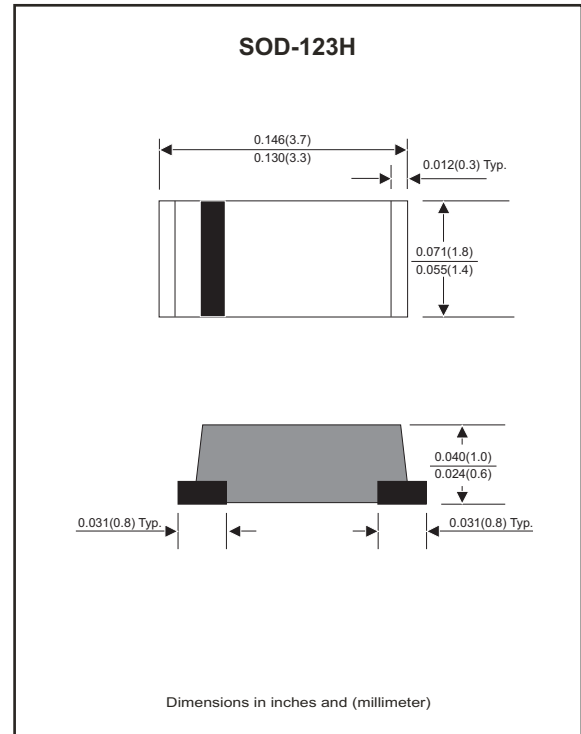


Features

- Halogen free.
- Excellent power dissipation offers better reverse leakage current and thermal resistance.
- Low profile surface mounted application in order to optimize board space.
- Low power loss,high efficiency.
- High current capability,low forward voltage drop.
- High surge capability.
- Guarding for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip,metal silicon junction.
- Lead-free parts meet environmental standards of MIL-STD-19500/228

Mechanical data

- Case: Molded plastic, SOD-123H/MINI SMA
- Epoxy: UL94-V0 rated flame retardant.
- Terminals: Solderable per MIL-STD-750, method 2026.
- Polarity: Indicated by cathode band.
- Mounting Position: any
- Weight: 0.011 grams approx.



Maximum Ratings (at T_A=25 °C unless otherwise noted)

Parameter		Symbol	CDBMT 120-HF	CDBMT 130-HF	CDBMT 140-HF	CDBMT 150-HF	CDBMT 160-HF	CDBMT 180-HF	CDBMT 1100-HF	CDBMT 1150-HF	Unit
Repetitive peak reverse voltage		V _{RRM}	20	30	40	50	60	80	100	150	V
Continuous reverse voltage		V _R	20	30	40	50	60	80	100	150	V
RMS voltage		V _{RMS}	14	21	28	35	42	56	70	105	V
Forward rectified current		I _O	1.0								A
Maximum forward voltage @ I _F =1.0A		V _F	0.50			0.70		0.85		0.92	V
Max. Forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		I _{FSM}	25								A
Max.Reverse current	V _R =V _{RRM} T _J =25°C	I _R	0.5								mA
	V _R =V _{RRM} T _J =100°C		10								
Typ. Thermal resistance (Junction to ambient)		R _{θJA}	98								°C/W
Typ. Diode Junction capacitance (Note 1)		C _J	120								pF
Operating temperature		T _J	-55 to +125			-55 to +150					°C
Storage temperature range		T _{STG}	-65 to +175								°C

Note : 1. F=1MHz and applied 4V DC reverse voltage

Rating and Characteristic Curves (CDBMT120-HF Thru. CDBMT1150-HF)

Fig.1- Current Derating Curve

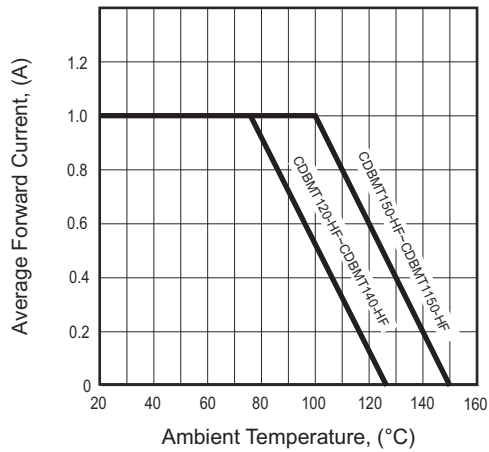


Fig.2 - Typical Forward Characteristics

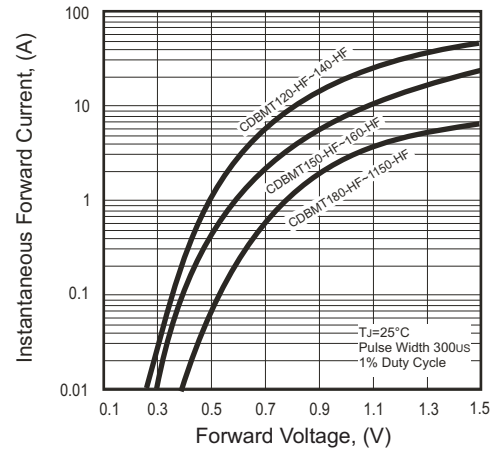


Fig.3 - Maximum Non-repetitive Forward Surge Current

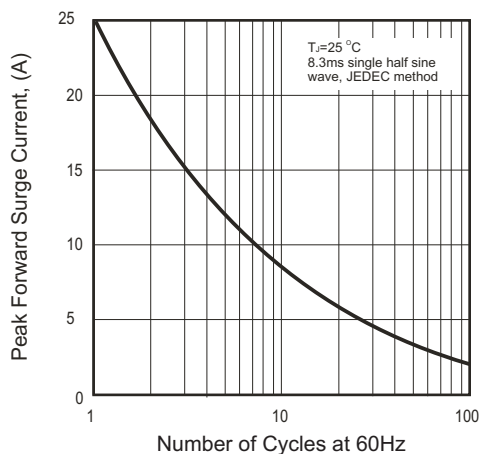


Fig.4 - Typical Junction Capacitance

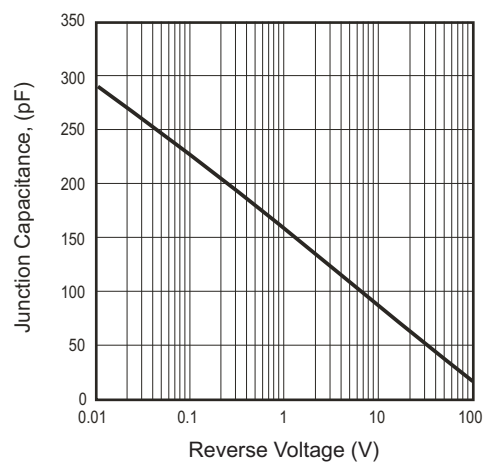
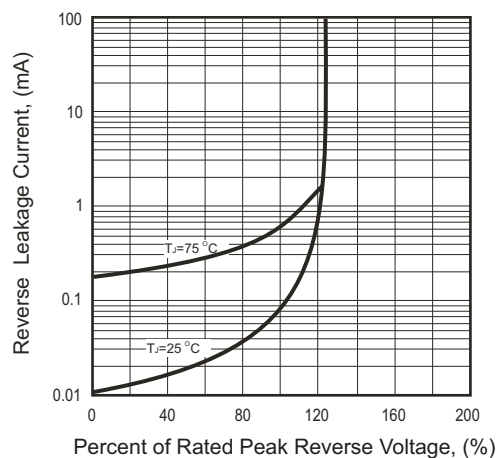
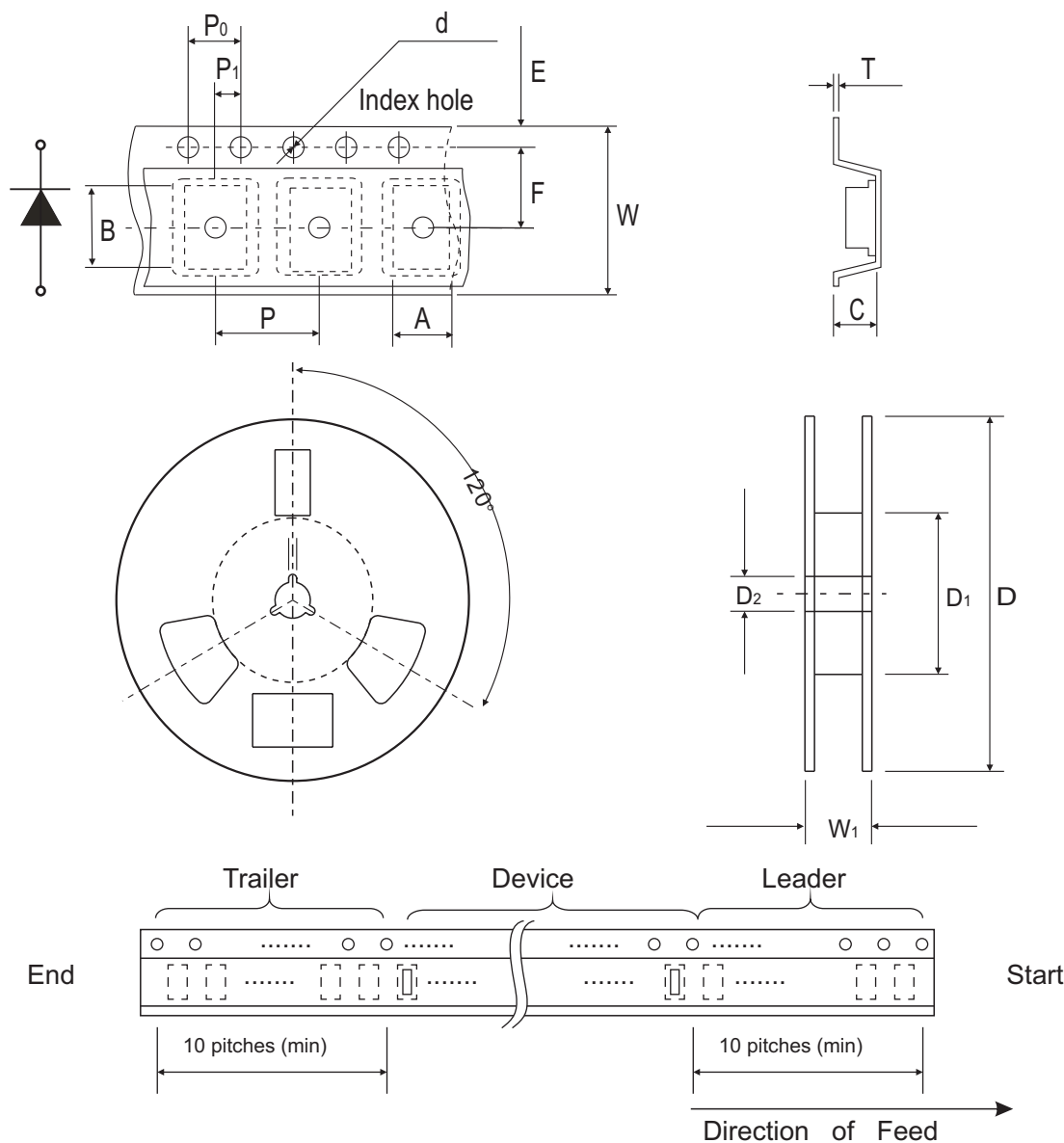


Fig.5 - Typical Reverse Characteristics



Reel Taping Specification



SOD-123H	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	2.00 ± 0.10	3.85 ± 0.10	1.10 ± 0.10	1.50 ± 0.10	178 ± 2.00	62.0 MIN.	13.0 ± 0.50
	(inch)	0.079 ± 0.004	0.152 ± 0.004	0.043 ± 0.004	0.059 ± 0.004	7.00 ± 0.079	2.440 MIN.	0.512 ± 0.020

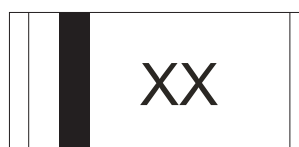
SOD-123H	SYMBOL	E	F	P	P0	P1	T	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	0.23 ± 0.10	8.00 ± 0.30	11.40 ± 1.0
	(inch)	0.069 ± 0.004	0.138 ± 0.004	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.009 ± 0.004	0.315 ± 0.012	0.449 ± 0.039

Pinning information

Pin	Simplified outline	Symbol
PIN 1 Cathode PIN 2 Anode		

Marking Code

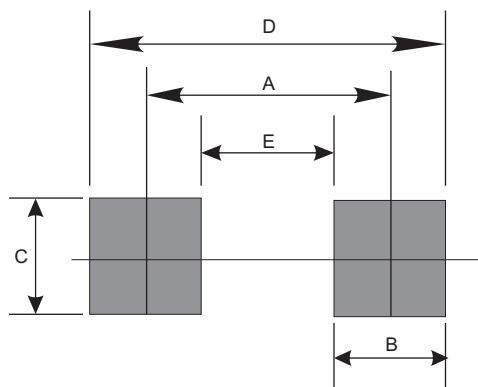
Part Number	Marking Code
CDBMT120-HF	12
CDBMT130-HF	13
CDBMT140-HF	14
CDBMT150-HF	15
CDBMT160-HF	16
CDBMT180-HF	18
CDBMT1100-HF	10
CDBMT1150-HF	115



xx / xxx = Product type marking code

Suggested PAD Layout

SIZE	SOD-123H	
	(mm)	(inch)
A	3.00	0.118
B	1.30	0.051
C	1.80	0.071
D	4.30	0.169
E	1.70	0.067



Standard Package

Case Type	Qty per Reel	Reel Size
	(Pcs)	(inch)
SOD-123H	3000	7